NSN 5962-01-336-0404

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View Online at https://aerobasegroup.com/nsn/5962-01-336-0404

Body Length: 1.280 inches Body Width: Between 0.220 inches and 0.310 inches Body Height: Between 0.140 inches and 0.185 inches Maximum Power Dissipation Rating: 1.0 watts Operating Tempurature Range: -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius Features Provided: Burn in and electrostatic sensitive and programmed Inclosure Material: Ceramic Inclosure Configuration: Dual-in-line Output Logic Form:
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Inclosure Material: Ceramic Inclosure Configuration: Dual-in-line
Ceramic Inclosure Configuration: Dual-in-line
Inclosure Configuration: Dual-in-line
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
D-9 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
14 printed circuit
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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